NTST40120CT, NTSJ40120CTG, NTSB40120CT-1G, NTSB40120CTG, NTSB40120CTT4G

Very Low Forward Voltage Trench-based Schottky Rectifier

Exceptionally Low $V_F = 0.43$ V at $I_F = 5$ A

Features

- Fine Lithography Trench–based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- Pb-Free and Halide-Free Packages are Available

Typical Applications

- Switching Power Supplies including Notebook/Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC–DC Converters
- Freewheeling and OR-ing Diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics

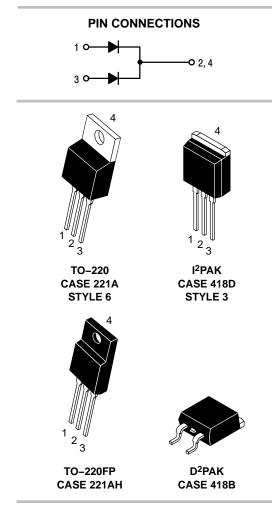
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec



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VERY LOW FORWARD VOLTAGE, LOW LEAKAGE SCHOTTKY BARRIER RECTIFIERS 40 AMPERES, 120 VOLTS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

NTST40120CT, NTSJ40120CTG, NTSB40120CT-1G, NTSB40120CTG, NTSB40120CTT4G

MAXIMUM RATINGS

Rating			Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	120	V
Average Rectified Forward Current (Rated V _R , T _C = 120°C)	Per Device Per Diode	I _{F(AV)}	40 20	A
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz, $T_C = 125^{\circ}C$)	Per Device Per Diode	I _{FRM}	80 40	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I _{FSM}	250	A
Operating Junction Temperature		TJ	-40 to +150	°C
Storage Temperature		T _{stg}	-40 to +150	°C
Voltage Rate of Change (Rated V _R)		dv/dt	10,000	V/µs

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

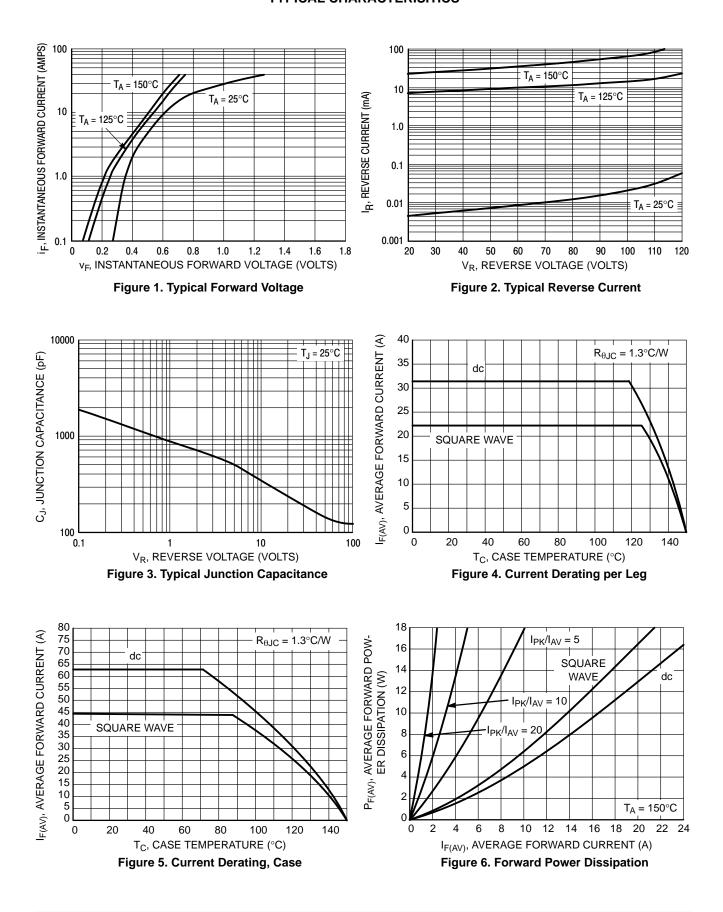
Rating	Symbol	NTST40120CTG, NTSB40120CT-1G	NTSB40120CTG	NTSJ40120CTG	Unit
Maximum Thermal Resistance per Diode Junction-to-Case Junction-to-Ambient	$R_{ heta JC} \ R_{ heta JA}$	1.3 70	0.79 46.3	4.0 105	°C/W °C/W

ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted)

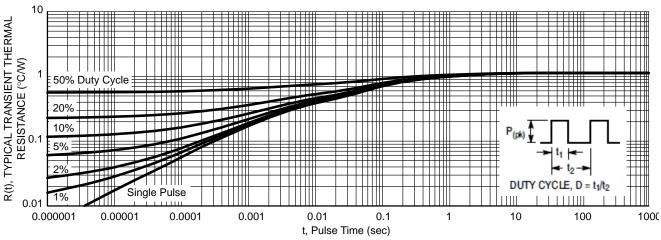
Rating	Symbol	Тур	Max	Unit
Maximum Instantaneous Forward Voltage (Note 1) ($I_F = 5 \text{ A}, T_J = 25^{\circ}\text{C}$)	۷ _F	0.50	-	V
(I _F = 10 A, T _J = 25°C) (I _F = 20 A, T _J = 25°C)		0.60 0.78	_ 0.91	
$(I_F = 5 A, T_J = 125^{\circ}C)$ $(I_F = 10 A, T_J = 125^{\circ}C)$ $(I_F = 20 A, T_J = 125^{\circ}C)$		0.43 0.53 0.63	_ _ 0.71	
Maximum Instantaneous Reverse Current (Note 1) ($V_R = 90 \text{ V}, T_J = 25^{\circ}\text{C}$) ($V_R = 90 \text{ V}, T_J = 125^{\circ}\text{C}$)	I _R	16 16		μA mA
(Rated dc Voltage, $T_J = 25^{\circ}C$) (Rated dc Voltage, $T_J = 125^{\circ}C$)		_ 30	500 100	μA mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Pulse Test: Pulse Width = $300 \ \mu$ s, Duty Cycle $\leq 2.0\%$

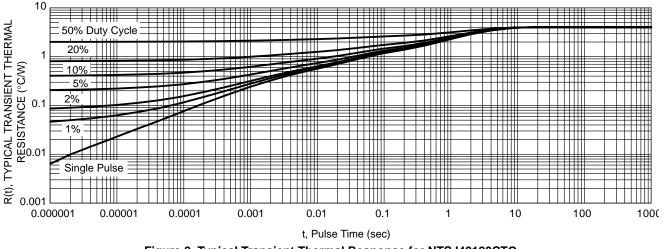
NTST40120CT, NTSJ40120CTG, NTSB40120CT-1G, NTSB40120CTG, NTSB40120CTT4G TYPICAL CHARACTERISITICS

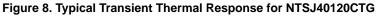


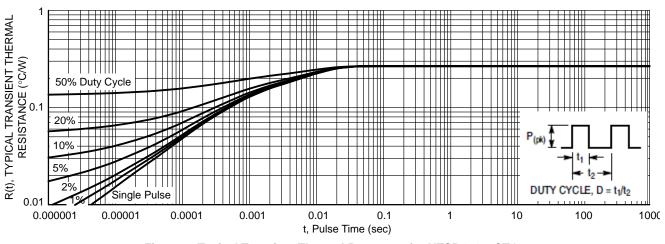
NTST40120CT, NTSJ40120CTG, NTSB40120CT-1G, NTSB40120CTG, NTSB40120CTT4G TYPICAL CHARACTERISITICS













NTST40120CT, NTSJ40120CTG, NTSB40120CT–1G, NTSB40120CTG, NTSB40120CTT4G

ORDERING INFORMATION

Device	Package	Shipping [†]
NTST40120CTG	TO-220 (Pb-Free)	50 Units / Rail
NTST40120CTH	TO–220 (Pb–Free and Halide–Free)	50 Units / Rail
NTSJ40120CTG	TO-220FP (Pb-Free and Halide-Free)	50 Units / Rail
NTSB40120CT-1G	l ² PAK (Pb–Free)	50 Units / Rail
NTSB40120CTG	D ² PAK (Pb–Free)	50 Units / Rail
NTSB40120CTT4G	D ² PAK (Pb-Free)	800 / Tape & Reel

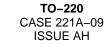
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

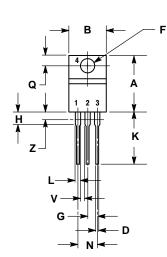
MARKING DIAGRAMS

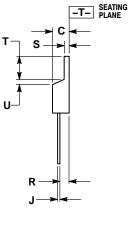
AYWW AYWW TS40120CG AYWW AYWW TS40120CG AKA TS40120Cx TS40120CG AKA AKA AKA I²PAK TO-220 TO-220FP D²PAK А = Assembly Location Y = Year WW = Work Week AKA = Polarity Designator = G or H х

- G = Pb–Free Package
- H = Halide–Free Package

NTST40120CT, NTSJ40120CTG, NTSB40120CT-1G, NTSB40120CTG, NTSB40120CTT4G PACKAGE DIMENSIONS







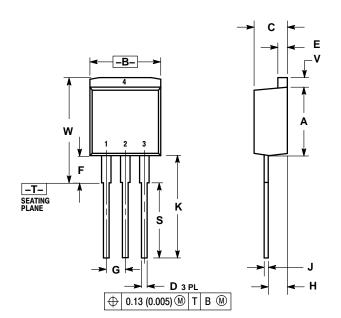
NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION 2 DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.415	9.66	10.53
С	0.160	0.190	4.07	4.83
D	0.025	0.038	0.64	0.96
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.161	2.80	4.10
J	0.014	0.024	0.36	0.61
Κ	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
۷	0.045		1.15	
Ζ		0.080		2.04

STYLE 6: PIN 1. ANODE 2. CATHODE 3. ANODE

CATHODE

I²PAK (TO-262) CASÈ 418D ISSUE D



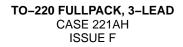
NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

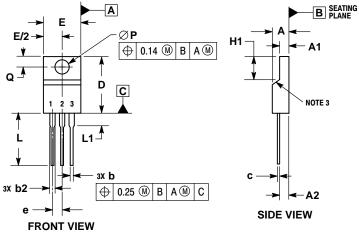
	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.335	0.380	8.51	9.65
В	0.380	0.406	9.65	10.31
С	0.160	0.185	4.06	4.70
D	0.026	0.035	0.66	0.89
Е	0.045	0.055	1.14	1.40
F	0.122 REF		3.10 REF	
G	0.100	BSC	2.54 BSC	
Η	0.094	0.110	2.39	2.79
J	0.013	0.025	0.33	0.64
Κ	0.500	0.562	12.70	14.27
S	0.390 REF		9.90	REF
۷	0.045	0.070	1.14	1.78
W	0.522	0.551	13.25	14.00

STYLE 3:

PIN 1. ANODE 2. CATHODE 3. ANODE 4. CATHODE

NTST40120CT, NTSJ40120CTG, NTSB40120CT-1G, NTSB40120CTG, NTSB40120CTT4G PACKAGE DIMENSIONS



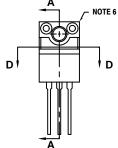


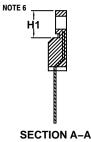
NOTES:

- DILGS.
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
- CONTOUR UNCONTROLLE DIN THIS AREA.
 CONTOUR UNCONTROLLE DIN THIS AREA.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH AND GATE PROTRUSIONS. MOLD FLASH AND GATE PROTRUSIONS NOT TO EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE TO BE MEASURED AT OUTERMOST EXTREME OF THE PLASTIC BODY.
 DIMENSION b2 DOES NOT INCLUDE DAMBAR PROTRUSION.
- 3. DIMENSION 02 DUES NOT INCLUDE DAMBAR PHOTHOSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 2.00. 6. CONTOURS AND FEATURES OF THE MOLDED PACKAGE BODY MAY VARY WITHIN THE ENVELOP DEFINED BY DIMENSIONS A1 AND H1 FOR MANUFACTURING PURPOSES.

	MILLIMETERS			
DIM	MIN MAX			
Α	4.30	4.70		
A1	2.50	2.90		
A2	2.50	2.90		
b	0.54	0.84		
b2	1.10	1.40		
c	0.49	0.79		
D	14.70	15.30		
Е	9.70	10.30		
е	2.54 BSC			
H1	6.60	7.10		
L	12.50	14.73		
L1		2.80		
Ρ	3.00	3.40		
Q	2.80	3.20		

F SECTION D-D

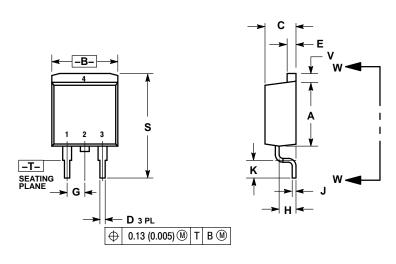




ALTERNATE CONSTRUCTION

NTST40120CT, NTSJ40120CTG, NTSB40120CT-1G, NTSB40120CTG, NTSB40120CTT4G PACKAGE DIMENSIONS

D²PAK 3 CASE 418B–04 ISSUE K

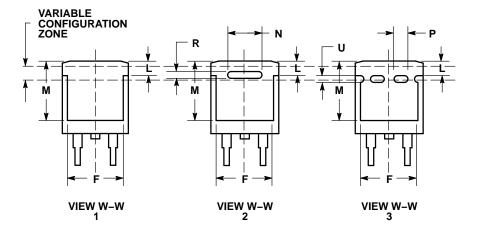


NOTES:

 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 CONTROLLING DIMENSION: INCH.
 418B–01 THRU 418B–03 OBSOLETE, NEW STANDARD 418B–04.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.340	0.380	8.64	9.65
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.83
D	0.020	0.035	0.51	0.89
Е	0.045	0.055	1.14	1.40
F	0.310	0.350	7.87	8.89
G	0.100 BSC		2.54	BSC
Н	0.080	0.110	2.03	2.79
J	0.018	0.025	0.46	0.64
κ	0.090	0.110	2.29	2.79
L	0.052	0.072	1.32	1.83
Μ	0.280	0.320	7.11	8.13
Ν	0.197 REF		5.00 REF	
Р	0.079 REF		2.00 REF	
R	0.039	REF	0.99 REF	
S	0.575	0.625	14.60	15.88
V	0.045	0.055	1.14	1.40



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